

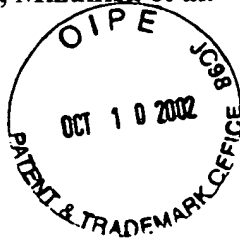
IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: NIHEI, Mizuhisa et al.

Serial No.: 09/746,064

Filed: December 26, 2000

For: SEMICONDUCTOR TRIODE DEVICE HAVING A
COMPOUND-SEMICONDUCTOR CHANNEL LAYER



Group Art Unit: 2815

Examiner: B. BAUMEISTER

P.T.O. Confirmation No.: 1990

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RESPONSE UNDER 37 CFR §1.116
- EXPEDITED RESPONSE -
GROUP ART UNIT 2815

BOX AF

Commissioner for Patents
Washington, D.C. 20231

October 10, 2002

Sir:

In response to the Office Action dated June 10, 2002, extended to October 10, 2002 by a one-month Petition for Extension of Time, please amend the above-identified application as follows:

IN THE CLAIMS:

Please CANCEL claims 1, 2 and 9 without prejudice or disclaimer of the subject matter recited therein.

Please AMEND claims 3 - 8 and 10 to read as follows:

3. (Amended) A compound semiconductor field effect transistor as claimed in claim 10, wherein said TiO₂ layer has a stoichiometric composition.

Sub E1
B.